

Vishay Semiconductors

Infrared Emitting Diode, 950 nm, GaAs

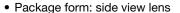


DESCRIPTION

The TSKS5400-FSZ is an infrared, 950 nm emitting diode in GaAs technology with high radiant power, molded in a clear plastic package.

FEATURES

· Package type: leaded





Peak wavelength: λ_p = 950 nm

High reliability

- High radiant power
- · High radiant intensity
- Angle of half intensity: $\varphi = \pm 30^{\circ}$
- · Low forward voltage
- · Suitable for high pulse current operation
- · Good spectral matching with Si photodetectors
- Package matched with detector TEKS5400
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

APPLICATIONS

- Photointerrupters
- · Transmissive sensors, gap sensors
- · Reflective sensors

PRODUCT SUMMARY					
COMPONENT	I _e (mW/sr)	φ (deg)	λ _p (nm)	t _r (ns)	
TSKS5400-FSZ	4.5	± 30	950	800	

Note

• Test conditions see table "Basic Characteristics"

ORDERING INFORM	IATION		
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM
TSKS5400-FSZ	Tape and ammopack	MOQ: 2000 pcs, 2000 pcs/ammopack	Side view lens

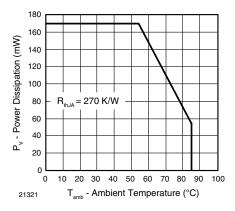
Note

MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Reverse voltage		V _R	6	V
Forward current		I _F	100	mA
Surge forward current	t _p ≤ 100 μs	I _{FSM}	2	А
Power dissipation		P _V	170	mW
Junction temperature		Tj	100	°C
Operating temperature range		T _{amb}	- 25 to + 85	°C
Storage temperature range		T _{stg}	- 40 to + 100	°C
Soldering temperature	t ≤ 5 s, 2 mm from case	T _{sd}	260	°C
Thermal resistance junction/ambient	J-STD-051, leads 7 mm, soldered on PCB	R _{thJA}	270	K/W









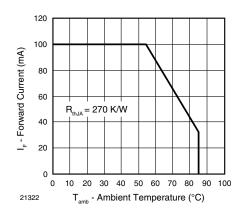


Fig. 2 - Forward Current Limit vs. Ambient Temperature

BASIC CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	$I_F = 100 \text{ mA}, t_p \le 20 \text{ ms}$	V_{F}		1.3	1.7	V
Reverse voltage	I _R = 10 μA	V_R	6			V
Temperature coefficient of V _F	I _F = 100 mA	TK _{VF}		- 1.3		mV/K
Junction capacitance	$V_R = 0 V, f = 1 MHz, E = 0$	Cj		30		pF
Radiant intensity	$I_F = 100 \text{ mA}, t_p \le 20 \text{ ms}$	l _e	2	4.5	7	mW/sr
Radiant power	$I_F = 50 \text{ mA}, t_p \le 20 \text{ ms}$	φ _e		10		mW
Temperature coefficient of φ _e	I _F = 50 mA	TKφ _e		- 0.8		%/K
Angle of half sensitivity		φ		± 30		deg
Peak wavelength	I _F = 50 mA	λ_{p}		950		nm
Spectral bandwidth	I _F = 50 mA	Δλ		50		nm
Diag time	I _F = 100 mA	t _r		800		ns
Rise time	$I_F = 1 \text{ A}, t_p/T = 0.01, t_p \le 10 \mu\text{s}$	t _r		450		ns

BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

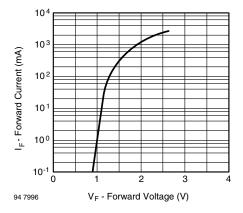


Fig. 3 - Pulse Forward Current vs. Forward Voltage

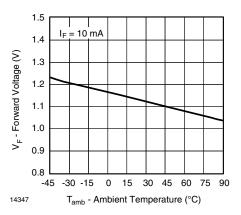
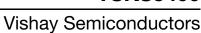


Fig. 4 - Forward Voltage vs. Ambient Temperature





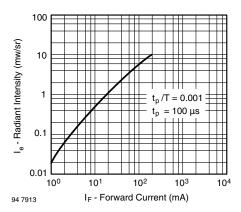


Fig. 5 - Radiant Intensity vs. Forward Current

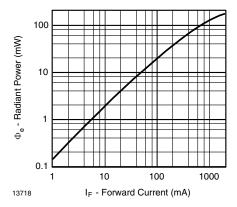


Fig. 6 - Radiant Power vs. Forward Current

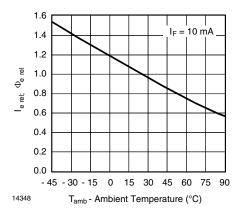


Fig. 7 - Relative Radiant Intensity vs. Ambient Temperature

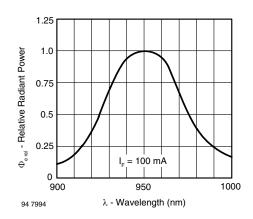


Fig. 8 - Relative Radiant Power vs. Wavelength

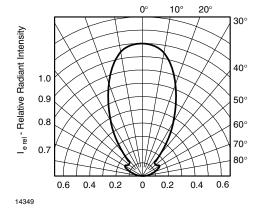
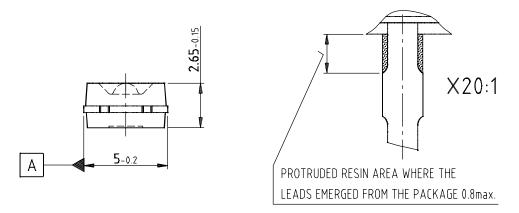
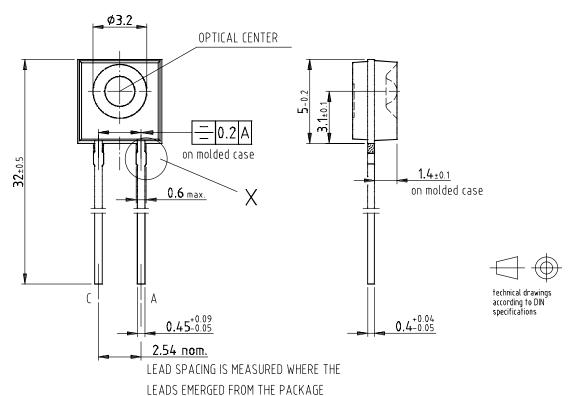


Fig. 9 - Relative Radiant Intensity vs. Angular Displacement



PACKAGE DIMENSIONS in millimeters





Drawing-No.: 6.544-5308.51-4

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